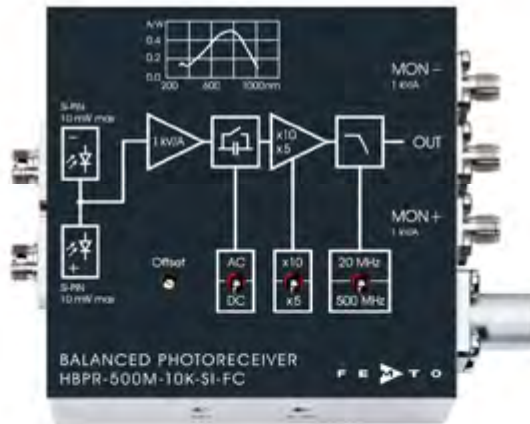




Datasheet

HBPR-500M-10K-SI-FC

High-Speed Balanced Photoreceiver



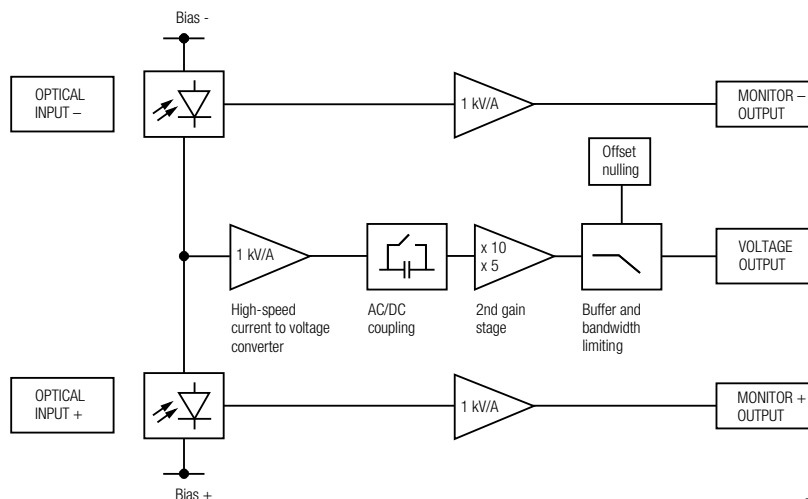
Features

- **Bandwidth DC to 500 MHz**
- **Common-Mode Rejection Ratio (CMRR) 45 dB typ.**
- **Si-PIN photodiodes**
- **FC fiber optic inputs**
- **Spectral range 320 – 1000 nm**
- **Very low NEP, down to 12 pW/√Hz**
- **Transimpedance gain switchable 5×10^3 V/A, 10×10^3 V/A**
- **High dynamic input range up to 2×10 mW balanced optical power**
- **Fast monitor outputs with 10 MHz bandwidth and 1×10^3 V/A gain**
- **Switchable low pass filter for minimizing wideband noise**
- **UNC 8-32 and M4 tapped holes for mounting on standard posts with metric and imperial thread**


Applications

- **Spectroscopy**
- **Heterodyne detection**
- **Optical coherence tomography (OCT)**
- **Optical delay measurement**
- **Differential optical front-end for oscilloscopes, spectrum analyzers, A/D converters and RF lock-in amplifiers**


Block Diagram



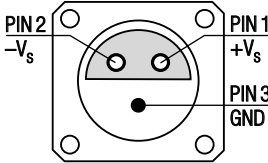
High-Speed Balanced Photoreceiver

<p>Intended Use</p>	<p>The HBPR-500M-10K-SI-FC photoreceiver consists of a combination of two anti-parallel connected photodiodes with a subsequent low-noise transimpedance amplifier. It is designed for fast conversion of the tiny difference of two optical signals into an equivalent output voltage. Operation is mostly self-explanatory. If in doubt, consult this document or contact support@femto.de.</p> <p>For safe operation, please refer to the damage thresholds specified in the "Absolute Maximum Ratings", "Temperature Range" and "Power Supply" sections of this document.</p> <p>The operating environment must be free of smoke, dust, grease, oil, condensing moisture, and other contaminants that could affect the operation or performance.</p>												
<p>Application Notes</p>	<p>The damage threshold of 12 mW for each photodiode mentioned in the "Absolute Maximum Ratings" section applies to reasonably homogeneous illumination of the photodiodes. Extreme focusing of the light beam can lead to damage to the photodiodes, even at significantly lower light power.</p> <p>To achieve optimum performance, it is recommended that the CW light intensity at both inputs be well balanced. The monitor outputs can be used for continuous balance control. For setups with arbitrarily varying CW offset, the photoreceiver's AC mode can be helpful. Using AC mode increases the CW offset range to 2.5 mW (@ 760 nm), regardless of the gain setting.</p>												
<p>Available Version</p>	<p>HBPR-500M-10K-SI-FC</p>  <p>Fix/permanent FC fiber connectors for high coupling efficiency, excellent conversion gain accuracy and common mode rejection ratio (CMRR)</p>												
<p>Related Models</p> <p>Si Versions</p>	<p>Various free space or fiber coupled HBPR models, with bandwidth up to 500 MHz, in the spectral range from 320 nm to 1700 nm are available.</p> <p>Fiber-coupled with fix/permanent FC fiber connectors</p> <table border="0"> <tr> <td>HBPR-100M-60K-SI-FC</td> <td>Si-PIN \varnothing 0.8 mm, DC – 100 MHz, 320 – 1000 nm, CMRR 50 dB, gain $2.0 \times 10^4 / 6.0 \times 10^4$ V/A switchable</td> </tr> <tr> <td>HBPR-200M-30K-SI-FC</td> <td>Si-PIN \varnothing 0.8 mm, DC – 200 MHz, 320 – 1000 nm, CMRR 45 dB, gain $1.0 \times 10^4 / 3.0 \times 10^4$ V/A switchable</td> </tr> <tr> <td>HBPR-500M-10K-SI-FC</td> <td>Si-PIN \varnothing 0.4 mm, DC – 500 MHz, 320 – 1000 nm, CMRR 40 dB, gain $5.0 \times 10^3 / 10.0 \times 10^3$ V/A switchable</td> </tr> </table> <p>Free space versions with 1.035"-40 threaded flanges</p> <table border="0"> <tr> <td>HBPR-100M-60K-SI-FST</td> <td>Si-PIN \varnothing 0.8 mm, DC – 100 MHz, 320 – 1000 nm, CMRR 50 dB, gain $2.0 \times 10^4 / 6.0 \times 10^4$ V/A switchable</td> </tr> <tr> <td>HBPR-200M-30K-SI-FST</td> <td>Si-PIN \varnothing 0.8 mm, DC – 200 MHz, 320 – 1000 nm, CMRR 45 dB, gain $1.0 \times 10^4 / 3.0 \times 10^4$ V/A switchable</td> </tr> <tr> <td>HBPR-500M-10K-SI-FST</td> <td>Si-PIN \varnothing 0.4 mm, DC – 500 MHz, 320 – 1000 nm, CMRR 40 dB, gain $5.0 \times 10^3 / 10.0 \times 10^3$ V/A switchable</td> </tr> </table>	HBPR-100M-60K-SI-FC	Si-PIN \varnothing 0.8 mm, DC – 100 MHz, 320 – 1000 nm, CMRR 50 dB, gain $2.0 \times 10^4 / 6.0 \times 10^4$ V/A switchable	HBPR-200M-30K-SI-FC	Si-PIN \varnothing 0.8 mm, DC – 200 MHz, 320 – 1000 nm, CMRR 45 dB, gain $1.0 \times 10^4 / 3.0 \times 10^4$ V/A switchable	HBPR-500M-10K-SI-FC	Si-PIN \varnothing 0.4 mm, DC – 500 MHz, 320 – 1000 nm, CMRR 40 dB, gain $5.0 \times 10^3 / 10.0 \times 10^3$ V/A switchable	HBPR-100M-60K-SI-FST	Si-PIN \varnothing 0.8 mm, DC – 100 MHz, 320 – 1000 nm, CMRR 50 dB, gain $2.0 \times 10^4 / 6.0 \times 10^4$ V/A switchable	HBPR-200M-30K-SI-FST	Si-PIN \varnothing 0.8 mm, DC – 200 MHz, 320 – 1000 nm, CMRR 45 dB, gain $1.0 \times 10^4 / 3.0 \times 10^4$ V/A switchable	HBPR-500M-10K-SI-FST	Si-PIN \varnothing 0.4 mm, DC – 500 MHz, 320 – 1000 nm, CMRR 40 dB, gain $5.0 \times 10^3 / 10.0 \times 10^3$ V/A switchable
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High-Speed Balanced Photoreceiver

<p>Related Models (continued)</p> <p>InGaAs Versions</p>	<p>Fiber-coupled with fix/permanent FC fiber connectors (ball lense coupled)</p> <p>HBPR-100M-60K-IN-FC InGaAs-PIN Ø 0.08 mm, DC – 100 MHz, 900 – 1700 nm, CMRR 55 dB, gain $2.0 \times 10^4 / 6.0 \times 10^4$ V/A switchable</p> <p>HBPR-200M-30K-IN-FC InGaAs-PIN Ø 0.08 mm, DC – 200 MHz, 900 – 1700 nm, CMRR 50 dB, gain $1.0 \times 10^4 / 3.0 \times 10^4$ V/A switchable</p> <p>Free space versions with 1.035"-40 threaded flanges</p> <p>HBPR-100M-60K-IN-FST InGaAs-PIN Ø 0.3 mm, DC – 100 MHz, 800 – 1700 nm, CMRR 50 dB, gain $2.0 \times 10^4 / 6.0 \times 10^4$ V/A switchable</p> <p>HBPR-200M-30K-IN-FST InGaAs-PIN Ø 0.3 mm, DC – 200 MHz, 800 – 1700 nm, CMRR 45 dB, gain $1.0 \times 10^4 / 3.0 \times 10^4$ V/A switchable</p> <p>HBPR-450M-10K-IN-FST InGaAs-PIN Ø 0.3 mm, DC – 450 MHz, 800 – 1700 nm, CMRR 35 dB, gain $5.0 \times 10^3 / 10.0 \times 10^3$ V/A switchable</p>
<p>Available Accessory</p>	<p>PS-15-25-L  Power Supply Input: 100 – 240 VAC Output: ±15 VDC</p>
<p>Specifications</p> <p>Gain</p> <p>Frequency Response</p> <p>Time Response</p> <p>Input</p> <p>Detector</p>	<p>Test conditions $V_S = \pm 15$ V, $T_A = 25$ °C, output load impedance 50 Ω, warm-up 20 minutes (min. 10 minutes recommended), monitor outputs terminated with 1 MΩ</p> <p>Transimpedance gain 5×10^3 V/A (@ 2nd gain ×5, 50 Ω load) 10×10^3 V/A (@ 2nd gain ×10, 50 Ω load)</p> <p>Gain accuracy ±1 % electrical</p> <p>Conversion gain 2.55×10^3 V/W typ. (@ 2nd gain ×5, 760 nm, 50 Ω load) 5.1×10^3 V/W typ. (@ 2nd gain ×10, 760 nm, 50 Ω load)</p> <p>Common mode rejection ratio (CMRR) 50 dB typ. (f ≤100 MHz) 40 dB typ. (f ≤500 MHz)</p> <p>Lower cut-off frequency DC / 10 Hz, switchable</p> <p>Upper cut-off frequency (–3 dB) 500 MHz (@ 2nd gain ×5), 460 MHz (@ 2nd gain ×10), switchable to 20 MHz</p> <p>Rise/fall time (10 % – 90 %) 0.85 ns (@ 2nd gain ×5); 0.95 ns (@ 2nd gain ×10) 17.5 ns (@ bandwidth set to 20 MHz)</p> <p>Noise equivalent power (NEP) minimum 12 pW/√Hz (@ 760 nm) 13 pW/√Hz (@ 760 nm, 20 MHz) 29 pW/√Hz (@ 760 nm, 200 MHz) 60 pW/√Hz (@ 760 nm, 500 MHz)</p> <p>Maximum differential CW power (for linear amplification) 400 μW (@ 2nd gain ×5, DC-coupled, 760 nm) 200 μW (@ 2nd gain ×10, DC-coupled, 760 nm) 2.5 mW (@ AC-coupled, 760 nm)</p> <p>Max. optical CW balanced power (common mode power) 10 mW (on each photodiode, @ 760 nm)</p> <p>Monitor optical saturation power (limited by maximum ratings) 12 mW (@ 760 nm)</p> <p>Detector type Si-PIN photodiode in FC fiber connector</p> <p>Active area Ø 400 μm, suitable for fibers up to 200 μm core diameter</p> <p>Spectral range 320 – 1000 nm</p> <p>Sensitivity 0.51 A/W typ. (@ 760 nm)</p>

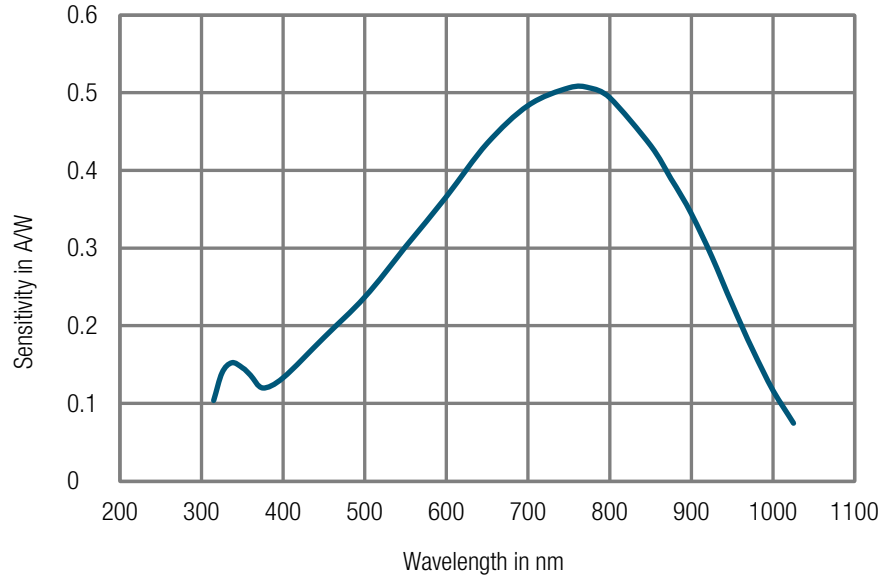
High-Speed Balanced Photoreceiver

Specifications (continued)			
Output	Output voltage range	± 1.0 V (@ 50 Ω load) for linear operation and low harmonic distortion	
	Max. output voltage	± 2.0 V (@ 50 Ω load)	
	Offset voltage compensation	± 100 mV typ., adjustable by offset potentiometer	
	Output impedance	50 Ω (terminate with 50 Ω load)	
	Slew rate	2800 V/ μ s	
	Max. output current	70 mA	
	Output reflection S22	-30 dB @ < 100 MHz -20 dB @ < 800 MHz	
	Output noise (typ.)	2.3 mV RMS (15 mV peak-peak) (@ 2 nd gain $\times 5$) 3.9 mV RMS (26 mV peak-peak) (@ 2 nd gain $\times 10$) 0.25 mV RMS (1.7 mV peak-peak) (@ 2 nd gain $\times 5$, BW 20 MHz) 0.4 mV RMS (2.5 mV peak-peak) (@ 2 nd gain $\times 10$, BW 20 MHz) (@ 50 Ω load, no signal on detectors, measurement bandwidth 2 GHz)	
	Monitor Outputs	Gain	1×10^3 V/A (@ ≥ 100 k Ω load)
		Voltage range	0 ... +10 V (@ ≥ 100 k Ω load)
Output impedance		50 Ω (terminate with ≥ 100 k Ω load)	
Max. output current		30 mA typ.	
Bandwidth		DC – 10 MHz	
Output noise		0.6 mV RMS (4 mV peak-peak) (@ 100 k Ω load, no signal on detectors, measurement bandwidth 200 MHz)	
Power Supply	Supply voltage	± 15 V (± 14.5 V ... ± 16.5 V)	
	Supply current	-90 / +120 mA typ. (depends on operating conditions, recommended power supply capability min. ± 200 mA)	
Optical Input Connector	Material FC receptacle	nickel silver	
Case	Weight	350 g (0.77 lbs)	
	Material	AlMg3Mn, nickel-plated	
Temperature Range	Storage temperature	-40 $^{\circ}$ C ... +85 $^{\circ}$ C	
	Operating temperature	0 $^{\circ}$ C ... +60 $^{\circ}$ C	
Absolute Maximum Ratings	Optical input power (CW)	12 mW (on each photodiode)	
	Power supply voltage	± 20 V	
Connectors	Inputs	FC fiber optic connectors (FC/PC and FC/APC compatible)	
	Outputs	SMA jacks (female)	
	Power supply	LEMO [®] series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52)	
 <p>PIN 2: -V_s PIN 1: +V_s PIN 3: GND</p> <p>Pin 1: +15 V Pin 2: -15 V Pin 3: GND</p>			
Scope of Delivery	HBPR-500M-10K-SI-FC, Lemo [®] 3-pin connector, 3 \times adapter SMA (male) to BNC (female), datasheet		
Ordering Information	HBPR-500M-10K-SI-FC	FC fiber optic connectors (FC/PC and FC/APC compatible)	

High-Speed Balanced Photoreceiver

Spectral Response

HBPR-500M-10K-SI-FC (FC fiber optic input)

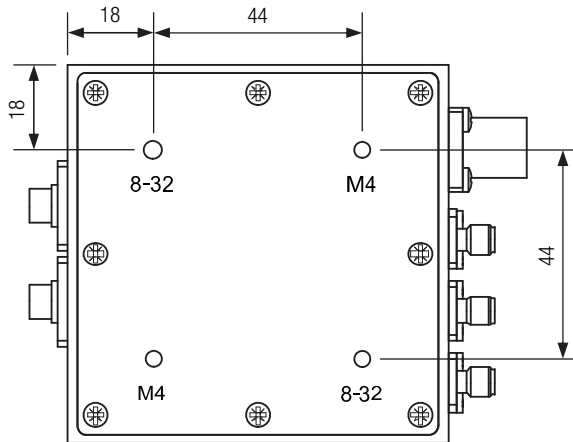
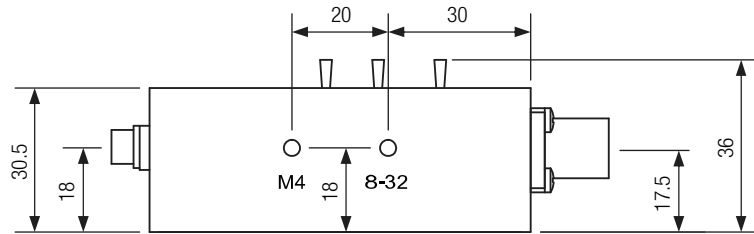
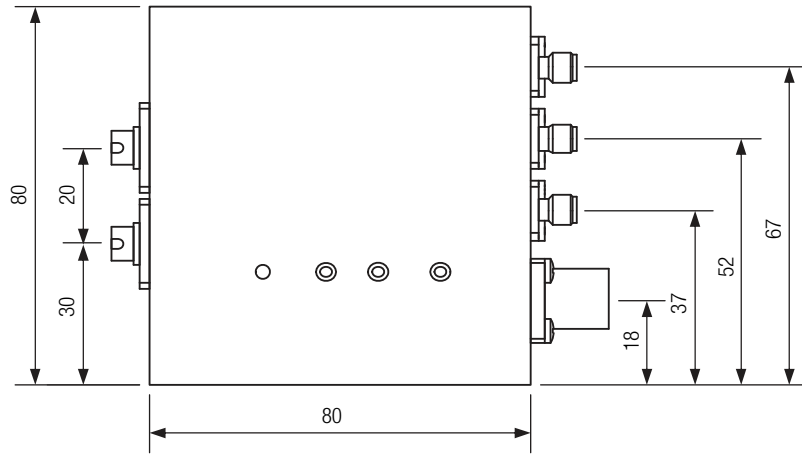


DB-Sens-HBPR-500-SI_R2

High-Speed Balanced Photoreceiver

Dimensions

HBPR-500M-10K-SI-FC



DZ-HBPR_FC_R2

all dimensions in mm unless otherwise noted

The base plate can be rotated if necessary. To do this, loosen the 8 screws.

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